

Fast CMOS 16-Bit Heavy Load Bidirectional Transceivers

Product Features:

- Very high-speed bidirectional transceiver for 150 pF heavy loads
- 16-bit switching in 5.5ns max
- $V_{CC} = 5V \pm 10\%$
- Hysteresis on all inputs
- Balanced output drivers: ± 24 mA
- Reduced system switching noise
- Typical V_{OLP} (Output Ground Bounce) $< 0.6V$ at $V_{CC} = 5V$, $T_A = 25^\circ C$
- Packages available:
 - 48-pin 240 mil wide plastic TSSOP (A)
 - 48-pin 300 mil wide plastic SSOP (V)
- Device models available on request

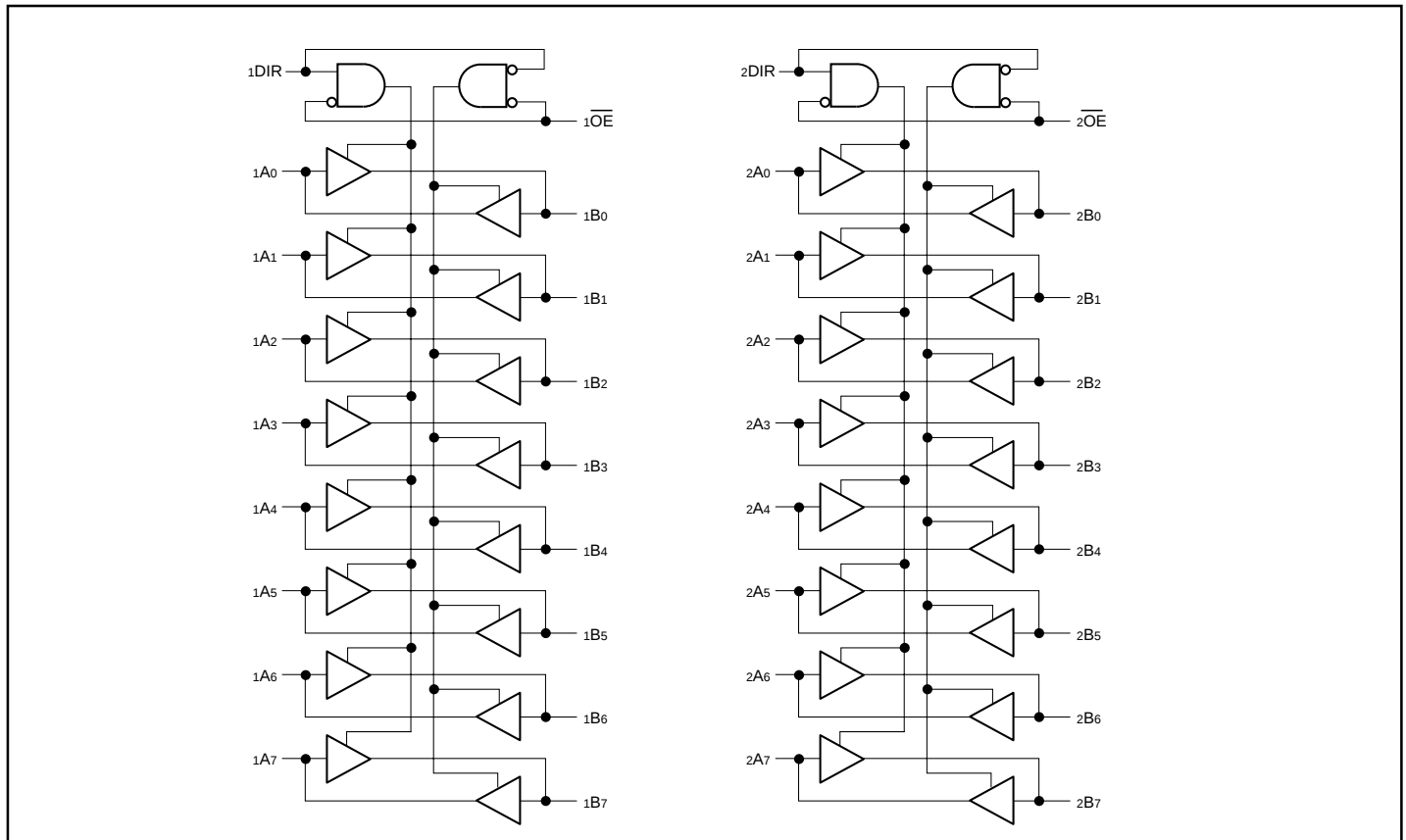
Product Description:

Pericom Semiconductor's PI74FCT series of logic circuits are produced in the Company's advanced 0.6 micron CMOS technology, achieving industry leading speed grades.

The PI74FCT162245MT is a 16-bit bidirectional transceivers designed for asynchronous two-way communication between data buses. The direction control input pin (xDIR) determines the direction of data flow through the bidirectional transceiver. The Direction and Output Enable controls are designed to operate these devices as either two independent 8-bit transceivers or one 16-bit transceiver. The output enable ($\overline{OE}$) input, when HIGH, disables both A and B ports by placing them in HIGH Z condition. It is designed specifically for heavy load applications.

The PI74FCT162245MT has ± 24 mA balanced output drivers. It is designed with current limiting resistors at its outputs to control the output edge rate resulting in lower ground bounce and undershoot. This eliminates the need for external terminating resistors for most interface applications.

Logic Block Diagram



Product Pin Description

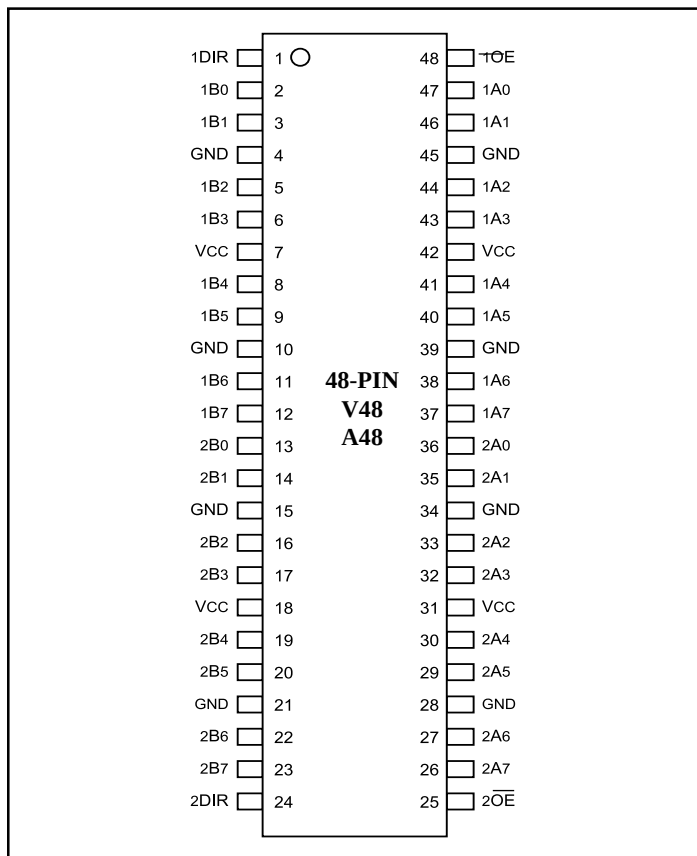
Pin Name	Description
$\overline{xOE}$	Output Enable Inputs (Active LOW)
$\overline{xDIR}$	Direction Control Input
$\overline{xAx}$	Side A Inputs or 3-State Outputs
$\overline{xBx}$	Side B Inputs or 3-State Outputs
GND	Ground
VCC	Power

Truth Table

Inputs ⁽¹⁾		Outputs ⁽¹⁾
$\overline{xOE}$	$\overline{xDIR}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	High Z State

Note: 1. H = High Voltage Level
 X = Don't Care
 L = Low Voltage Level
 Z = High Impedance

Product Pin Configuration



Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	–65°C to +150°C
Ambient Temperature with Power Applied	–40°C to +85°C
Supply Voltage to Ground Potential (Inputs & V _{CC} Only)	–0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only)	–0.5V to +7.0V
DC Input Voltage	–0.5V to +7.0V
DC Output Current	120 mA
Power Dissipation	1.0W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics (Over the Operating Range, T_A = –40°C to +85°C, V_{CC} = 5.0V ± 10%)

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Typ ⁽²⁾	Max.	Units
V _{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level		2.0			V
V _{IL}	Input LOW Voltage	Guaranteed Logic LOW Level				0.8	V
I _{IH}	Input HIGH Current	V _{CC} = Max.	V _{IN} = V _{CC}			1	μA
I _{IL}	Input LOW Current	V _{CC} = Max.	V _{IN} = GND			–1	μA
I _{OZH}	High Impedance	V _{CC} = Max.	V _{OUT} = 2.7V			1	μA
I _{OZL}	Output Current	V _{CC} = Max.	V _{OUT} = 0.5V			–1	μA
V _{IK}	Clamp Diode Voltage	V _{CC} = Min., I _{IN} = –18 mA			–0.7	–1.2	V
I _{OS}	Short Circuit Current	V _{CC} = Max. ⁽³⁾ , V _{OUT} = GND		–80	–140	–200	mA
I _O	Output Drive Current	V _{CC} = Max. ⁽³⁾ , V _{OUT} = 2.5V		–50		–180	mA
V _H	Input Hysteresis				100		mV

Output Drive Characteristics (Over the Operating Range)

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Typ ⁽²⁾	Max.	Units
V _{OH}	Output HIGH Voltage	V _{CC} = Min., V _{IN} = V _{IH} or V _{IL}	I _{OH} = –24.0 mA	2.4	3.3		V
V _{OL}	Output LOW Voltage	V _{CC} = Min., V _{IN} = V _{IH} or V _{IL}	I _{OL} = 24 mA		0.3	0.55	V
I _{ODL}	Output LOW Current	V _{CC} = 5V, V _{IN} = V _{IH} or V _{IL} , V _{OUT} = 1.5V ⁽³⁾		60	115	150	mA
I _{ODH}	Output HIGH Current	V _{CC} = 5V, V _{IN} = V _{IH} or V _{IL} , V _{OUT} = 1.5V ⁽³⁾		–60	–115	–150	mA

Capacitance (T_A = 25°C, f = 1 MHz)

Parameters ⁽⁴⁾	Description	Test Conditions	Typ	Max.	Units
C _{IN}	Input Capacitance	V _{IN} = 0V	4.5	6	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	5.5	8	pF

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V_{CC} = 5.0V, +25°C ambient and maximum loading.
3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
4. This parameter is determined by device characterization but is not production tested.

Power Supply Characteristics

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Typ ⁽²⁾	Max.	Units
I _{CC}	Quiescent Power Supply Current	V _{CC} = Max.	V _{IN} = GND or V _{CC}		0.1	500	μA
ΔI _{CC}	Supply Current per Input @ TTL HIGH	V _{CC} = Max.	V _{IN} = 3.4V ⁽³⁾		0.5	1.5	mA
I _{CCD}	Supply Current per Input per MHz ⁽⁴⁾	V _{CC} = Max., Outputs Open x $\overline{OE}$ = xDIR = GND One Bit Toggling 50% Duty Cycle	V _{IN} = V _{CC} V _{IN} = GND		60	100	μA/ MHz
I _C	Total Power Supply Current ⁽⁶⁾	V _{CC} = Max., Outputs Open f _I = 10 MHz 50% Duty Cycle x $\overline{OE}$ = xDIR = GND One Bit Toggling	V _{IN} = V _{CC} V _{IN} = GND		0.6	1.5 ⁽⁵⁾	mA
			V _{IN} = 3.4V V _{IN} = GND		0.9	2.3 ⁽⁵⁾	
		V _{CC} = Max., Outputs Open f _I = 2.5 MHz 50% Duty Cycle x $\overline{OE}$ = xDIR = GND 16 Bits Toggling	V _{IN} = V _{CC} V _{IN} = GND		2.4	4.5 ⁽⁵⁾	
			V _{IN} = 3.4V V _{IN} = GND		6.4	16.5 ⁽⁵⁾	

Notes:

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- Typical values are at V_{CC} = 5.0V, +25°C ambient.
- Per TTL driven input (V_{IN} = 3.4V); all other inputs at V_{CC} or GND.
- This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.
- I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}

$$I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_I N_I)$$

I_{CC} = Quiescent Current
ΔI_{CC} = Power Supply Current for a TTL High Input (V_{IN} = 3.4V)
D_H = Duty Cycle for TTL Inputs High
N_T = Number of TTL Inputs at D_H
I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)
f_I = Input Frequency
N_I = Number of Inputs at f_I
All currents are in milliamps and all frequencies are in megahertz.

PI74FCT162245MT Switching Characteristics over Operating Range — High-Load Condition

Parameters	Description	Conditions ⁽¹⁾	162245MT		Unit
			Com.		
			Min	Max	
tPLH tPHL	Propagation Delay ⁽²⁾ xAX to xBx	CL = 150 pF All 16 Bits Switching	1.5	5.5	ns
tpZH tpZL	Output Enable Time xOE to xAX or xBx	CL = 50 pF RL = 500Ω	1.5	6.2	ns
tpHZ tplZ	Output Disable Time ⁽³⁾ xOE to xAX or xBx		1.5	5.6	ns
tsk(o)	Output Skew ⁽⁴⁾		—	0.5	ns

Notes:

1. See test circuit and wave forms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. This parameter is guaranteed but not production tested.
4. Skew between any two outputs, of the same package, switching in the same direction. This parameter is guaranteed by design.